

PNZ109L (PN109L)

Silicon planar type

For optical control systems

■ Features

- High sensitivity: $I_L = 3.5 \text{ mA (min.)}$
- Built-in filter to cutoff visible light for reducing ambient light noise
- Peak sensitivity wavelength matched with infrared light emitting devices: $\lambda_p = 900 \text{ nm (typ.)}$
- Fast response: $t_r = 5 \text{ } \mu\text{s (typ.)}$
- Long lifetime, high reliability

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-emitter voltage (Base open)	V_{CEO}	20	V
Collector-base voltage (Emitter open)	V_{CBO}	30	V
Emitter-collector voltage (Base open)	V_{ECO}	3	V
Emitter-base voltage (Collector open)	V_{EBO}	5	V
Collector current	I_C	30	mA
Collector power dissipation *	P_C	150	mW
Operating ambient temperature	T_{opr}	-25 to +85	$^\circ\text{C}$
Storage temperature	T_{stg}	-30 to +100	$^\circ\text{C}$

Note) *: The rate of electric power reduction is $1.5 \text{ mW}/^\circ\text{C}$ above $T_a = 25^\circ\text{C}$.

■ Electrical-Optical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Photocurrent *1	I_L	$V_{CE} = 10 \text{ V}, L = 100 \text{ lx}$	3.5			mA
Collector-emitter cutoff current (Base open)	I_{CEO}	$V_{CE} = 10 \text{ V}$		0.05	2.0	μA
Collector-emitter saturation voltage *1	$V_{CE(sat)}$	$I_L = 1 \text{ mA}, L = 500 \text{ lx}$		0.3	0.6	V
Peak sensitivity wavelength	λ_{PD}	$V_{CE} = 10 \text{ V}$		900		nm
Half-power angle	θ	The angle when the photocurrent is halved		10		$^\circ$
Rise time *2	t_r	$V_{CC} = 10 \text{ V}, I_L = 5 \text{ mA}, R_L = 100 \text{ } \Omega$		5		μs
Fall time *2	t_f			6		μs

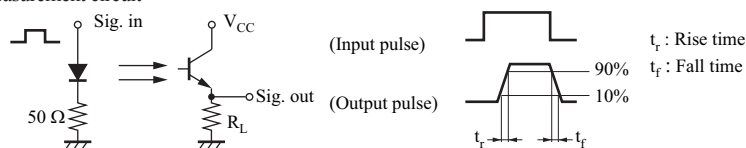
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. Spectral sensitivity characteristics: Sensitivity for wave length over 400 nm maximum sensitivity ratio is 100%.

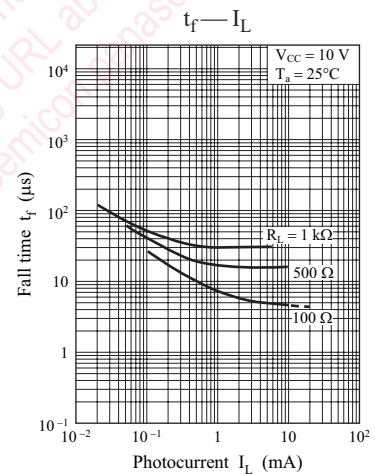
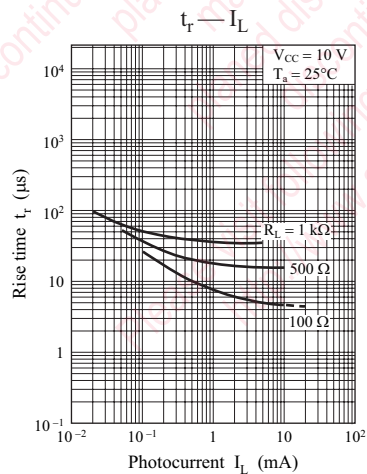
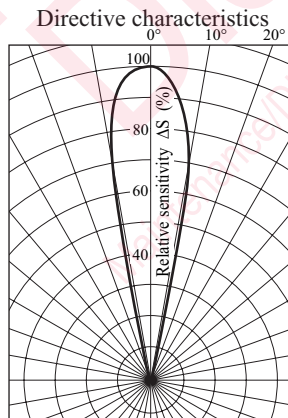
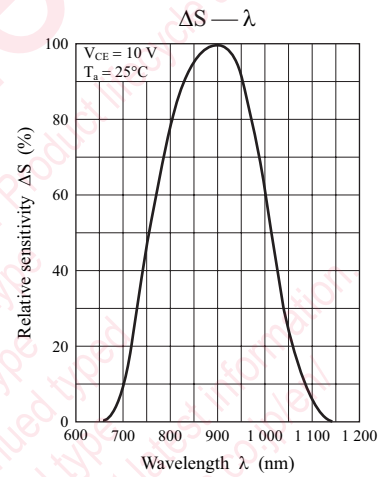
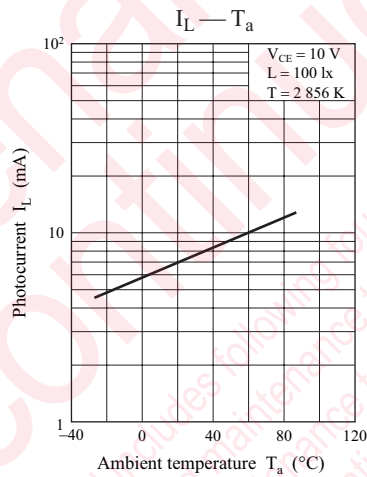
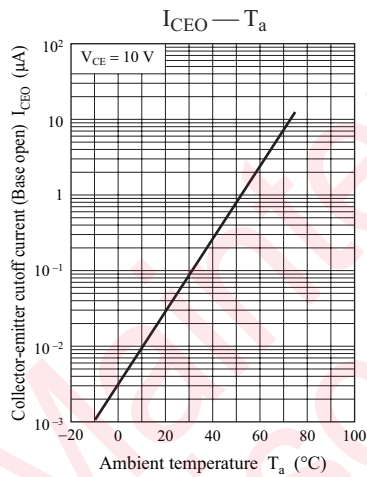
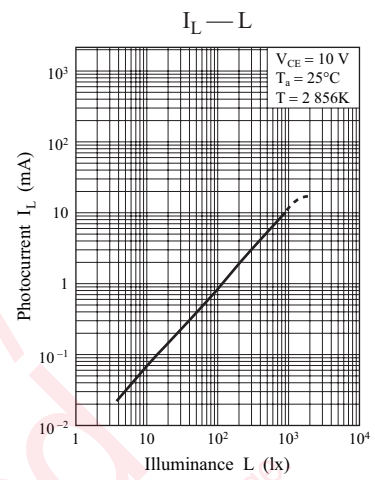
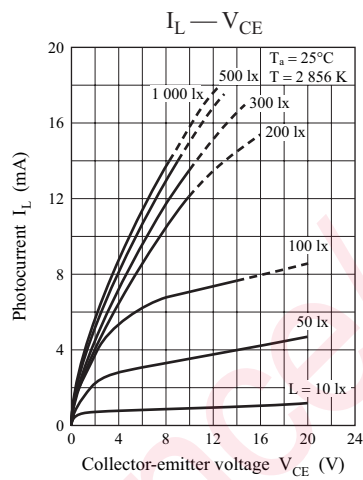
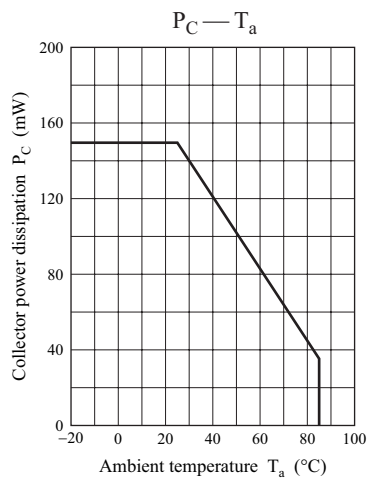
3. This device is designed by disregarding radiation.

4. *1:Source: Tungsten lamp (color temperature 2 856K)

*2: Switching time measurement circuit

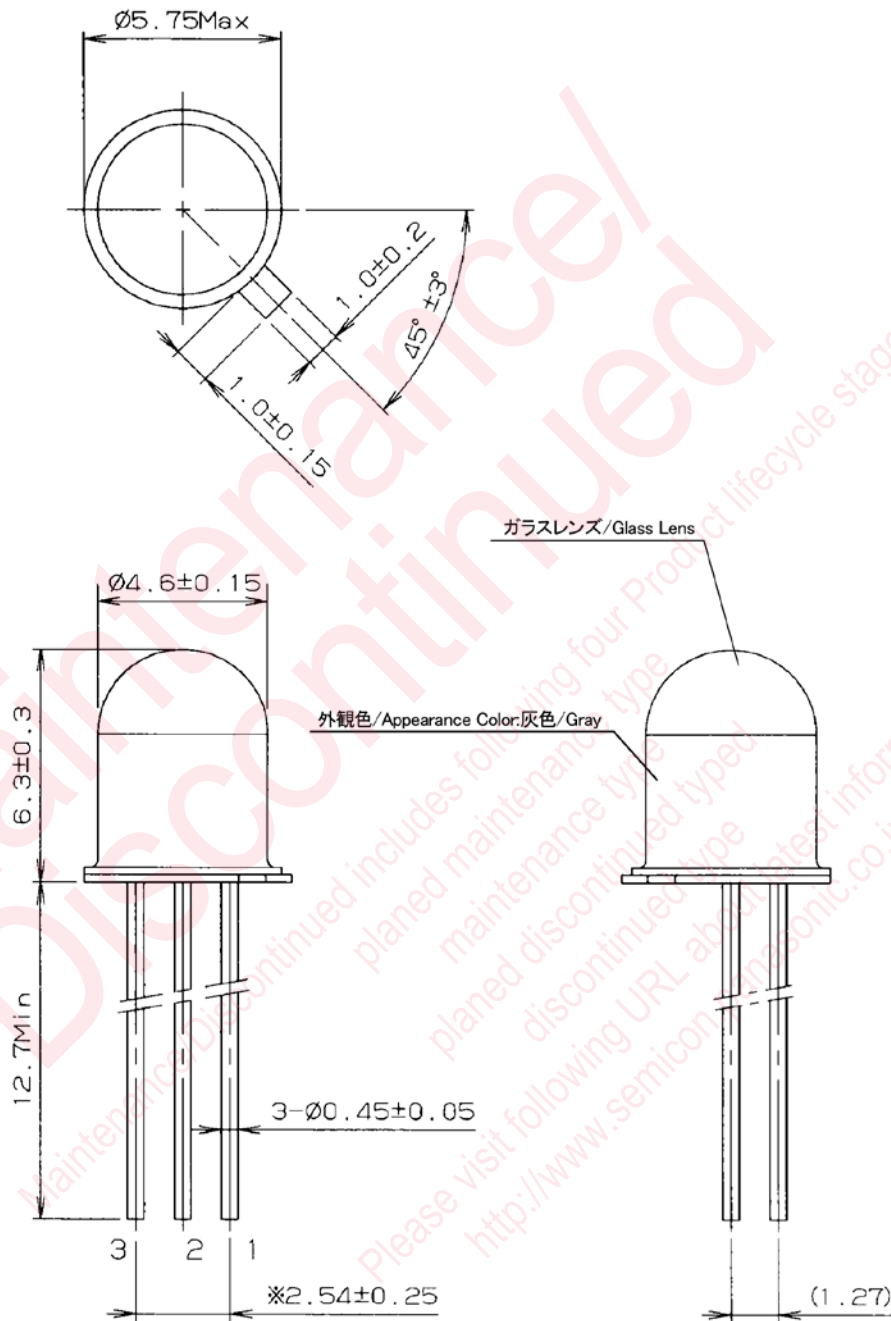


Note) The part number in the parenthesis shows conventional part number.



■ Package (Unit: mm)

MPCLTN3S0001



(注 1)※リード根元寸法とする。／(Note1)※Indicates root dimensions of lead.

• Pin name

- 1: Emitter
- 2: Base
- 3: Collector

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